

RS12xxA/RS12xxB 12A TRIACs

DESCEIPTION:

High current density due to double mesa technology, SIPOS and Glass Passivation.

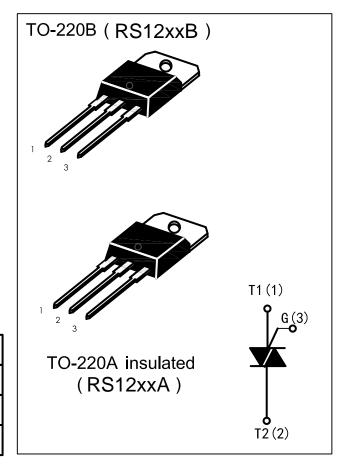
RS12xx series triacs is suitable for or for phase contol operation, light dimmers,motor speed ON/OFF function in applications such as static relays, general purpose AC switching,They can be used as an heating regulation,induction motor stating circuits...controll ers.

RS12xx-TW -SW -CW -BW are 3 quadrants triacs, They are specially recommended for use on inductive loads

RS12xx are isolated in internally.they provide a 2500V RMS isolation voltage from all three terminals to external heat sink.

MAIN FEATURES

Symbol	Value	Unit	
IT(RMS)	12	Α	
Vdrm/Vrrm	600and800	V	
Vтм	≤1.55	V	



ABSOLUTE MAXIMUM RATINGS

Parameter			Value	Unit
Storage junction temperature range Operrating junction temperature range			-40 to +150 -40 to +125	°C
Repetitive Peak Off-state Voltage Repetitive Peak Reverse Voltage	Tj=25°C	Vdrm Vrrm	600and800 600and800	V
Non repetitive Surge Peak Off-state Voltage Non repetitive Peak Reverse Voltage Tj=25°C			700and900 700and900	V
RMS on-state current (full sine wave)	TO-220AB Tc=105°C TO-220AB Ins Tc=90°C	IT(RMS)	12	Α
Non repetitive surge peak on-state current (full cycle,Tj=25°C)	Ітѕм	120 126	Α	
I ² t Value for fusing tp=10ms			78	A ² s
Critical rate of rise of on-state current IG=2×IGT, tr≤100 ns, f=120Hz, Tj=125°C			50	A/us
Peak gate current tp=20us,	lgм	4	Α	
Average gate power dissipation	Tj=125°C	PG(AV)	1	W



ELECTRICAL CHARACTERISTICS(Tj=25°C unless otherwise specified)

3 Quadrants

Symbol	Test Condition	Quadrant RS12xxB/RS12			S12xx	άA	Unit	
				TW	SW	CW	BW	
lGī	\/- 10\/ B. 200	1 - 11 - 111	MAX.	5	10	35	50	mA
VGT	VD=12V RL=30Ω	1 - 11 - 111	MAX.	1.3			٧	
VGD	VD=VDRM RL=3.3KΩ I - II - III Tj=125℃		MIN	0.2			V	
IL	IG=1.2IGT	I - III	MAX.	10	25	50	70	4
		II		15	30	60	80	mA
lΗ	IT=100mA		MAX.	10	15	35	50	mA
dV/dt	VD=67%VDRM gate open Tj=125°C		MIN.	20	40	500	1000	V/µs
(dl/dt)c	(dV/dt) c=0.1V/µs Tj=125℃		MIN.	3.5	6.5			A/ms
	(dV/dt) c=10V/µs Tj=125℃			1.0	2.9			
	Without snubber Tj=125℃					6.5	12	

4 Quadrants

Symbol	Test Condition	Quadrant		RS12xxB	Unit	
				С	В	
lgī	V 10V 5 000	- - V	MAX.	25 50	50 100	mA
VGT	VD=12V RL=30Ω	ALL	MAX.	1.3		٧
VGD	VD=VDRM RL=3.3KΩ Tj=125℃	ALL	MIN.	0.2		٧
lL	IG=1.2IGT	I - III - IV	MAX.	40	50	- mA
		II		80	100	
ΙH	IT=100mA		MAX.	25	50	mA
dV/dt	VD=67%VDRM gate open Tj=125°C		MIN.	200	400	V/µs
(dl/dt)c	(dV/dt) c=0.1V/µs Tj=125℃		MIN.			
	(dV/dt) c=10V/µs Tj=125℃					
	Without snubber Tj=125°					



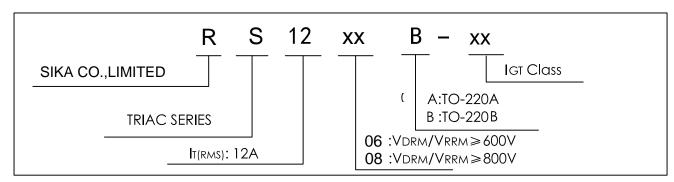
STATIC CHARACTERISTICS

Symbol	Test Conditions	Value (MAX)	Unit	
VTM	Itm=17A, tp=380uS	Tj=25℃	1.55	V
I DRM	VD=VDRM	Tj=25℃	5	uA
Irrm	V _R =V _{RRM}	Tj=125℃	1	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit	
Rth(j-c)	Junction to case (AC)	TO-220AB	1.4	°C/W
		TO-220AB Insulated	2.3	

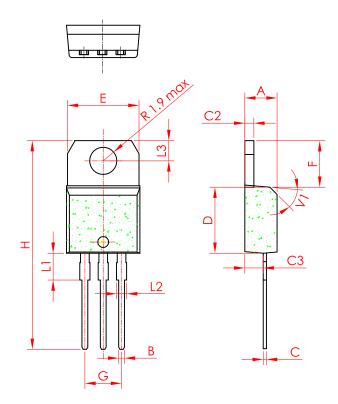
ORDERING INFORMATION





PACKAGE MECHANICAL DATA

TO-220AB



	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Мах.	Min.	Тур.	Max.	
Α	4.4		4.6	0.173		1.181	
В	0.61		0.88	0.024		0.034	
С	0.49		0.70	0.019		0.027	
C2	1.23		1.32	0.048		0.051	
C3	2.4		2.72	0.094		0.107	
D	8.6		9.7	0.338		0.382	
Е	10		10.4	0.393		0.409	
F	6.2		6.6	0.244		0.259	
G	4.8		5.4	0.189		0.213	
Н	28.0		29.8	11.0		11.7	
L1		3.75			0.147		
L2	1.14		1.7	0.044		0.066	
L3	2.65		2.95	0.104		0.116	
V1		40°			40°		

Fig. 1: Maximum power dissipation versus RMS on-state current(full cycle)

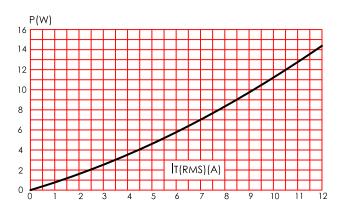


Fig. 3: on-state characteristics (maximum values)

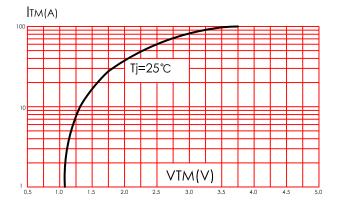


Fig. 5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10mS

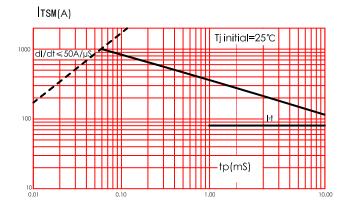


Fig. 2: RMS on-state current versus case temperrature(full cycle)

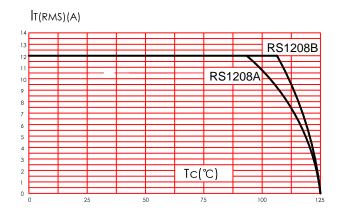


Fig. 4: Surge peak on-state current versus number of cycyles

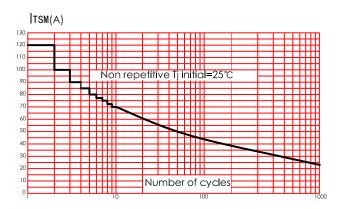


Fig. 6: Relative variation of gate trigger currunt, holding current and latching current versus junction temperature(typical values)

